



**1200V 75A**  
**APT75DQ120B**      **APT75DQ120S**  
**APT75DQ120BG\***   **APT75DQ120SG\***

\*G Denotes RoHS Compliant, Pb Free Terminal Finish.

**ULTRAFAST SOFT RECOVERY RECTIFIER DIODE**

**PRODUCT APPLICATIONS**

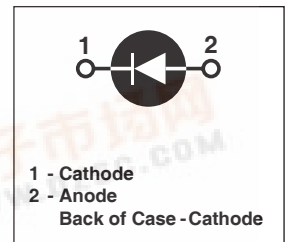
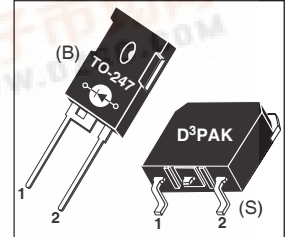
- Anti-Parallel Diode
  - Switchmode Power Supply
  - Inverters
- Free Wheeling Diode
  - Motor Controllers
  - Converters
  - Inverters
- Snubber Diode
- PFC

**PRODUCT FEATURES**

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- Popular TO-247 Package or Surface Mount D<sup>3</sup>PAK Package
- Low Forward Voltage
- Low Leakage Current
- Avalanche Energy Rated

**PRODUCT BENEFITS**

- Low Losses
- Low Noise Switching
- Cooler Operation
- Higher Reliability Systems
- Increased System Power Density



**MAXIMUM RATINGS**

All Ratings:  $T_C = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT75DQ120B(G) S(G)	UNIT
$V_R$	Maximum D.C. Reverse Voltage	1200	Volts
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		
$V_{RWM}$	Maximum Working Peak Reverse Voltage		
$I_{F(AV)}$	Maximum Average Forward Current ( $T_C = 113^\circ\text{C}$ , Duty Cycle = 0.5)	75	Amps
$I_{F(RMS)}$	RMS Forward Current (Square wave, 50% duty)	121	
$I_{FSM}$	Non-Repetitive Forward Surge Current ( $T_J = 45^\circ\text{C}$ , 8.3ms)	540	
$E_{AVL}$	Avalanche Energy (1A, 40mH)	20	mJ
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to 175	$^\circ\text{C}$
$T_L$	Lead Temperature for 10 Sec.	300	

**STATIC ELECTRICAL CHARACTERISTICS**

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT	
$V_F$	Forward Voltage		$I_F = 75\text{A}$	2.8	3.1	Volts
			$I_F = 150\text{A}$	3.48		
			$I_F = 75\text{A}, T_J = 125^\circ\text{C}$	2.17		
$I_{RM}$	Maximum Reverse Leakage Current		$V_R = 1200\text{V}$		100	$\mu\text{A}$
			$V_R = 1200\text{V}, T_J = 125^\circ\text{C}$		500	
$C_T$	Junction Capacitance, $V_R = 200\text{V}$		50		pF	

**DYNAMIC CHARACTERISTICS**

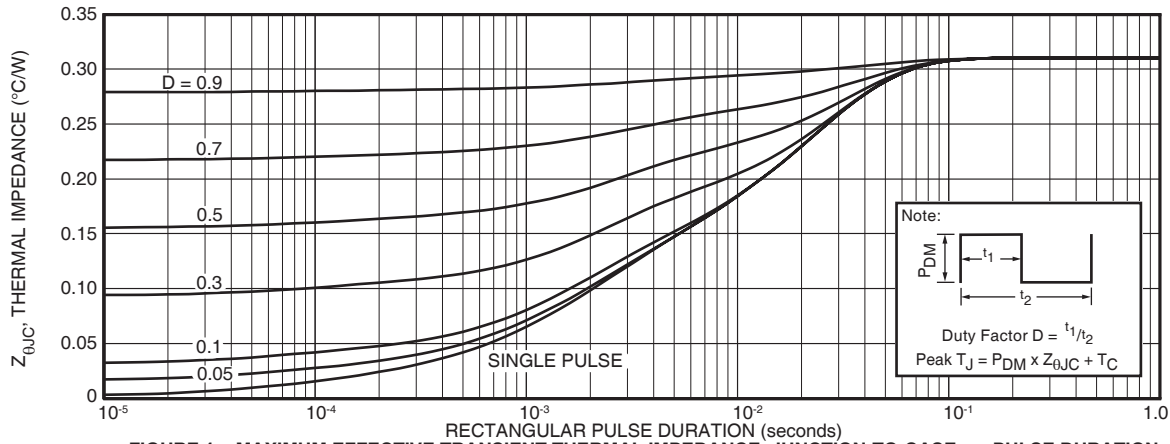
**APT75DQ120B(G)\_S(G)**

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
$t_{rr}$	Reverse Recovery Time	$I_F = 1A, di_F/dt = -100A/\mu s, V_R = 30V, T_J = 25^\circ C$	-	32		ns
$t_{rr}$	Reverse Recovery Time		-	325		
$Q_{rr}$	Reverse Recovery Charge	$I_F = 75A, di_F/dt = -200A/\mu s, V_R = 800V, T_C = 25^\circ C$	-	715		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	5	-	Amps
$t_{rr}$	Reverse Recovery Time		-	420		ns
$Q_{rr}$	Reverse Recovery Charge	$I_F = 75A, di_F/dt = -200A/\mu s, V_R = 800V, T_C = 125^\circ C$	-	3340		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	13	-	Amps
$t_{rr}$	Reverse Recovery Time		-	195		ns
$Q_{rr}$	Reverse Recovery Charge	$I_F = 75A, di_F/dt = -1000A/\mu s, V_R = 800V, T_C = 125^\circ C$	-	5810		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	42		Amps

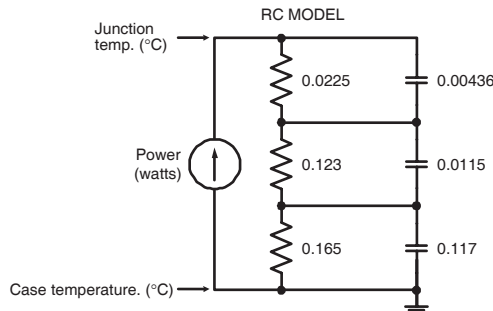
**THERMAL AND MECHANICAL CHARACTERISTICS**

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			.31	$^\circ C/W$
$W_T$	Package Weight		0.22		oz
			5.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

APT Reserves the right to change, without notice, the specifications and information contained herein.



**FIGURE 1a. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION**



**FIGURE 1b. TRANSIENT THERMAL IMPEDANCE MODEL**

# TYPICAL PERFORMANCE CURVES

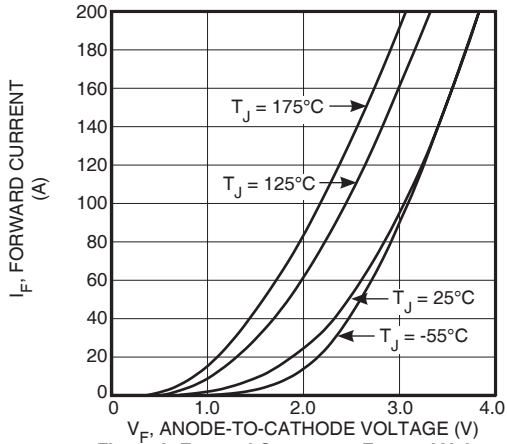


Figure 2. Forward Current vs. Forward Voltage

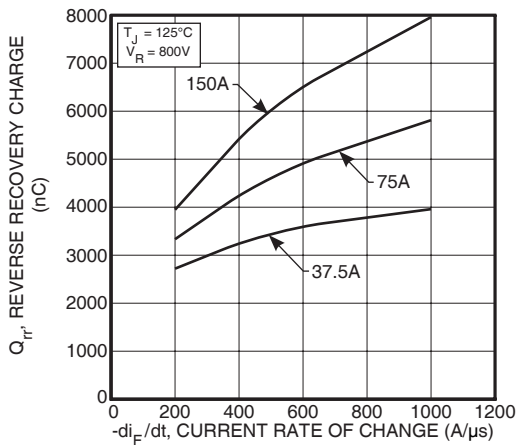


Figure 4. Reverse Recovery Charge vs. Current Rate of Change

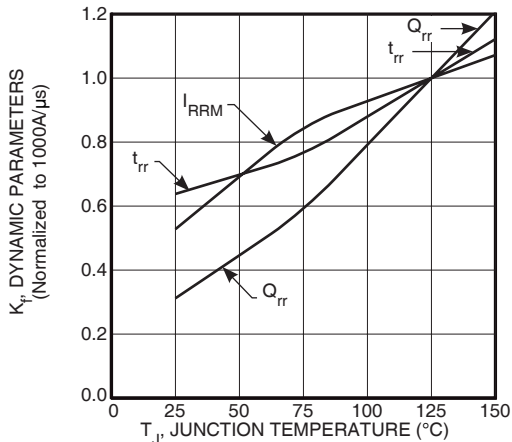


Figure 6. Dynamic Parameters vs. Junction Temperature

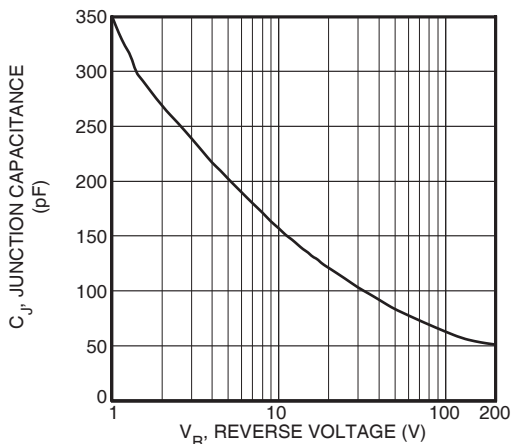


Figure 8. Junction Capacitance vs. Reverse Voltage

# APT75DQ120B(G)\_S(G)

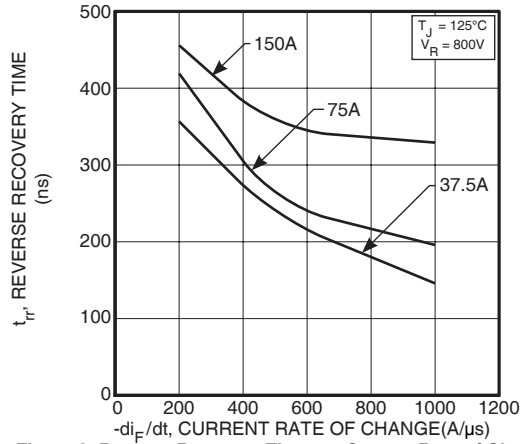


Figure 3. Reverse Recovery Time vs. Current Rate of Change

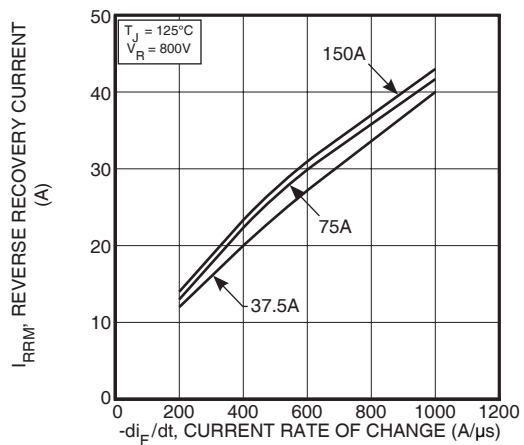


Figure 5. Reverse Recovery Current vs. Current Rate of Change

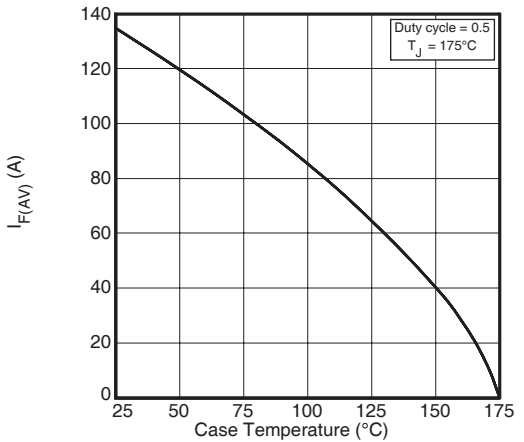


Figure 7. Maximum Average Forward Current vs. Case Temperature

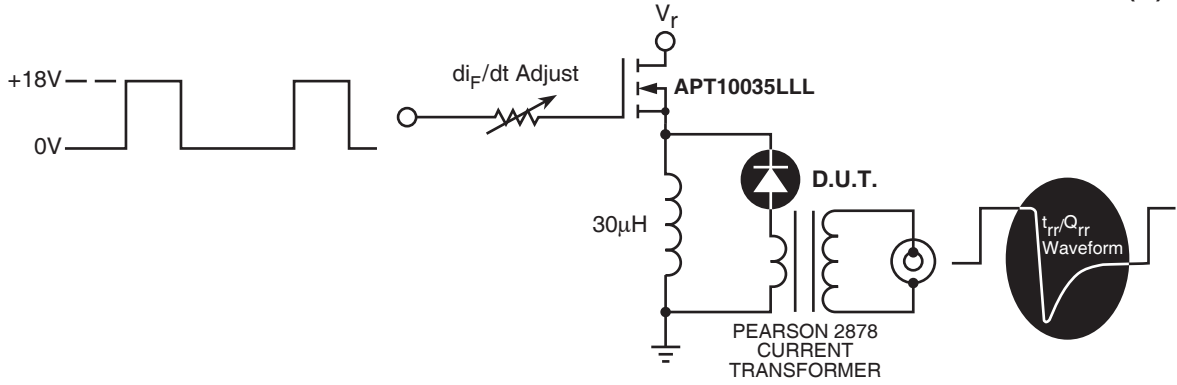


Figure 9. Diode Test Circuit

- 1  $I_F$  - Forward Conduction Current
- 2  $di_F/dt$  - Rate of Diode Current Change Through Zero Crossing.
- 3  $I_{RRM}$  - Maximum Reverse Recovery Current.
- 4  $t_{rr}$  - Reverse Recovery Time, measured from zero crossing where diode current goes from positive to negative, to the point at which the straight line through  $I_{RRM}$  and  $0.25 \cdot I_{RRM}$  passes through zero.
- 5  $Q_{rr}$  - Area Under the Curve Defined by  $I_{RRM}$  and  $t_{rr}$ .

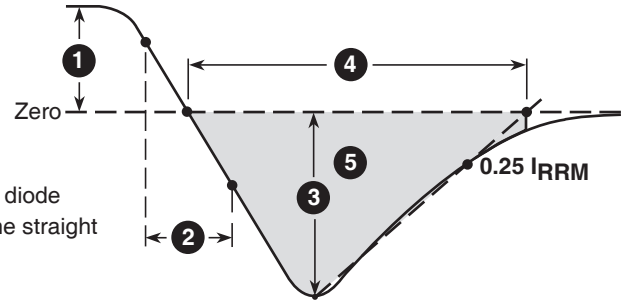
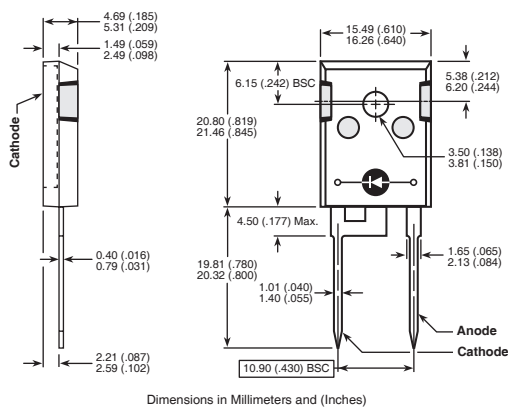


Figure 10, Diode Reverse Recovery Waveform and Definitions

**TO-247 Package Outline**

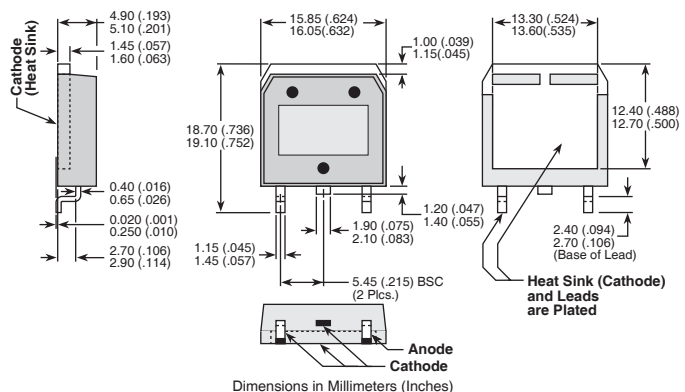
(e1) SAC: Tin, Silver, Copper



Dimensions in Millimeters and (Inches)

**D<sup>3</sup>PAK Package Outline**

(e3) 100% Sn



Dimensions in Millimeters (Inches)